

# MPSA13, MPSA14

MPSA14 is a Preferred Device

## Darlington Transistors

### NPN Silicon



ON Semiconductor®

<http://onsemi.com>

#### Features

- Pb-Free Packages are Available\*

勝特力材料 886-3-5753170  
勝特力电子(上海) 86-21-34970699  
勝特力电子(深圳) 86-755-83298787  
[Http://www.100y.com.tw](http://www.100y.com.tw)

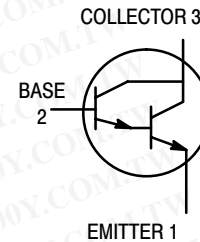
#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CES}$	30	Vdc
Collector-Base Voltage	$V_{CBO}$	30	Vdc
Emitter-Base Voltage	$V_{EBO}$	10	Vdc
Collector Current - Continuous	$I_C$	500	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	1.5 12	W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

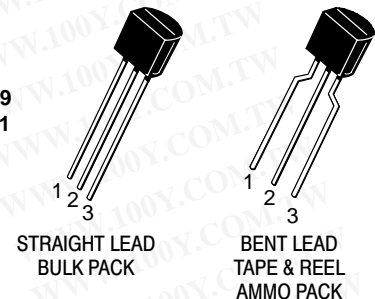
#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{mW}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{mW}$

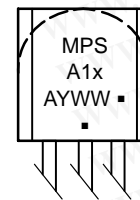
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



TO-92  
CASE 29  
STYLE 1



#### MARKING DIAGRAM



- x = 3 or 4
- A = Assembly Location
- Y = Year
- WW = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MPSA13, MPSA14

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector–Emitter Breakdown Voltage ( $I_C = 100\ \mu\text{A}$ , $I_B = 0$ )	$V_{(BR)CES}$	30	–	Vdc
Collector Cutoff Current ( $V_{CB} = 30\ \text{Vdc}$ , $I_E = 0$ )	$I_{CBO}$	–	100	nA
Emitter Cutoff Current ( $V_{EB} = 10\ \text{Vdc}$ , $I_C = 0$ )	$I_{EBO}$	–	100	nA
<b>ON CHARACTERISTICS (Note 1)</b>				
DC Current Gain ( $I_C = 10\ \text{mA}$ , $V_{CE} = 5.0\ \text{Vdc}$ )  ( $I_C = 100\ \text{mA}$ , $V_{CE} = 5.0\ \text{Vdc}$ )	$h_{FE}$	MPSA13 5,000 MPSA14 10,000 MPSA13 10,000 MPSA14 20,000	– – – –	–
Collector–Emitter Saturation Voltage ( $I_C = 100\ \text{mA}$ , $I_B = 0.1\ \text{mA}$ )	$V_{CE(sat)}$	–	1.5	Vdc
Base–Emitter On Voltage ( $I_C = 100\ \text{mA}$ , $V_{CE} = 5.0\ \text{Vdc}$ )	$V_{BE(on)}$	–	2.0	Vdc
<b>SMALL–SIGNAL CHARACTERISTICS</b>				
Current–Gain – Bandwidth Product (Note 2) ( $I_C = 10\ \text{mA}$ , $V_{CE} = 5.0\ \text{Vdc}$ , $f = 100\ \text{MHz}$ )	$f_T$	125	–	MHz

1. Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$ .

2.  $f_T = |h_{fe}| \cdot f_{test}$ .

## ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MPSA13	TO–92	5000 Units / Bulk
MPSA13G	TO–92 (Pb–Free)	5000 Units / Bulk
MPSA13RLRA	TO–92	2000 / Tape & Reel
MPSA13RLRAG	TO–92 (Pb–Free)	2000 / Tape & Reel
MPSA13RLRMG	TO–92 (Pb–Free)	2000 / Ammo Pack
MPSA13RLRPG	TO–92 (Pb–Free)	2000 / Ammo Pack
MPSA13ZL1G	TO–92 (Pb–Free)	2000 / Ammo Pack
MPSA14G	TO–92 (Pb–Free)	5000 Units / Bulk
MPSA14RLRAG	TO–92 (Pb–Free)	2000 / Tape & Reel
MPSA14RLRPG	TO–92 (Pb–Free)	2000 / Ammo Pack

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MPSA13, MPSA14

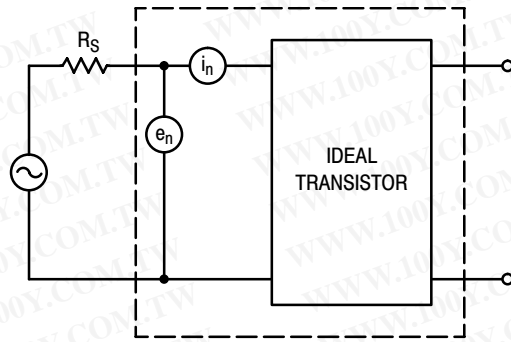


Figure 1. Transistor Noise Model

## NOISE CHARACTERISTICS

( $V_{CE} = 5.0 \text{ Vdc}$ ,  $T_A = 25^\circ\text{C}$ )

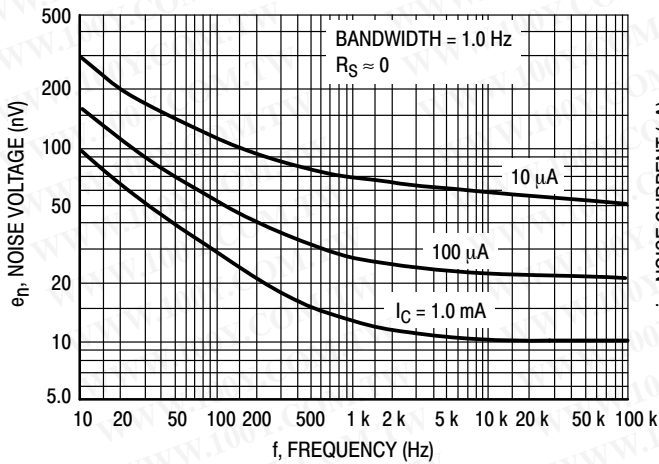


Figure 2. Noise Voltage

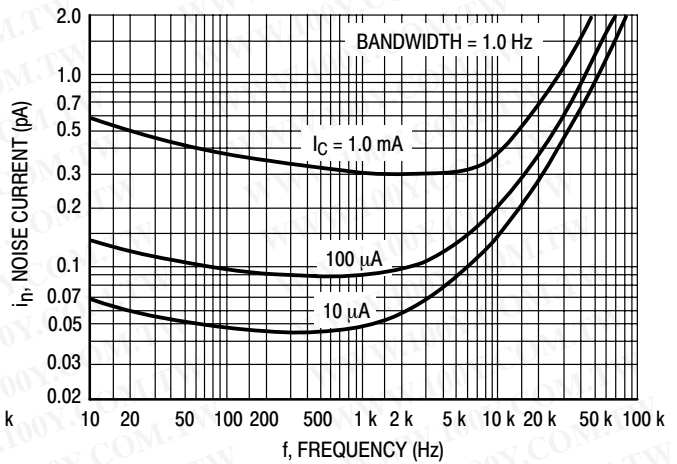


Figure 3. Noise Current

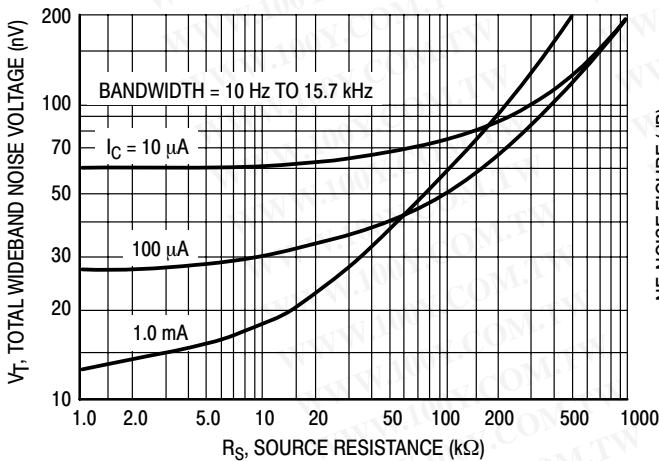


Figure 4. Total Wideband Noise Voltage

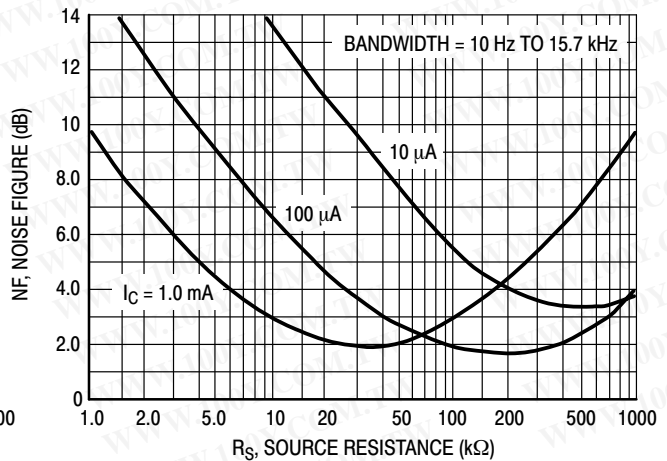


Figure 5. Wideband Noise Figure

# MPSA13, MPSA14

## SMALL-SIGNAL CHARACTERISTICS

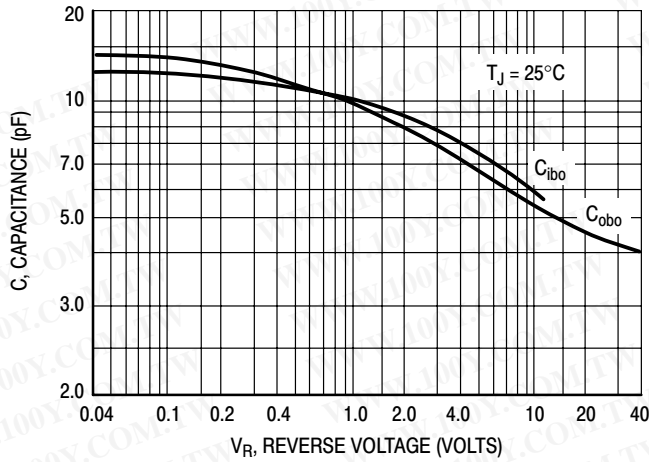


Figure 6. Capacitance

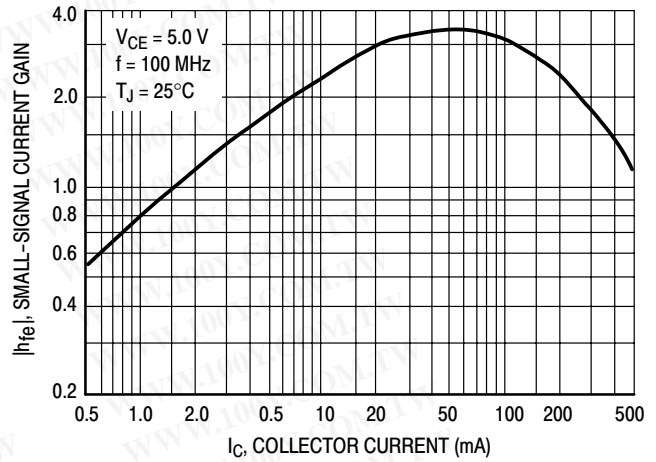


Figure 7. High Frequency Current Gain

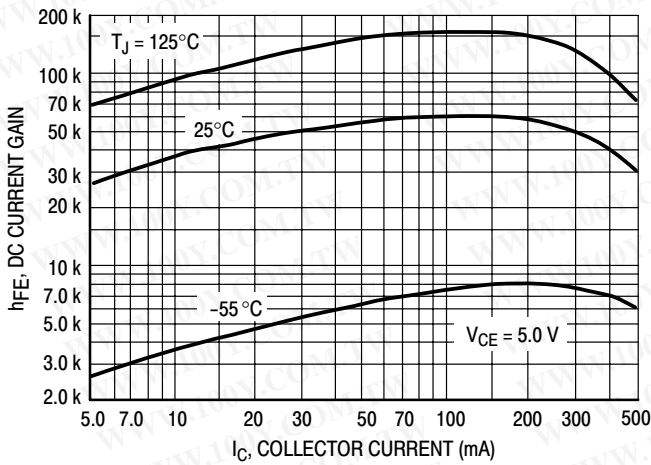


Figure 8. DC Current Gain

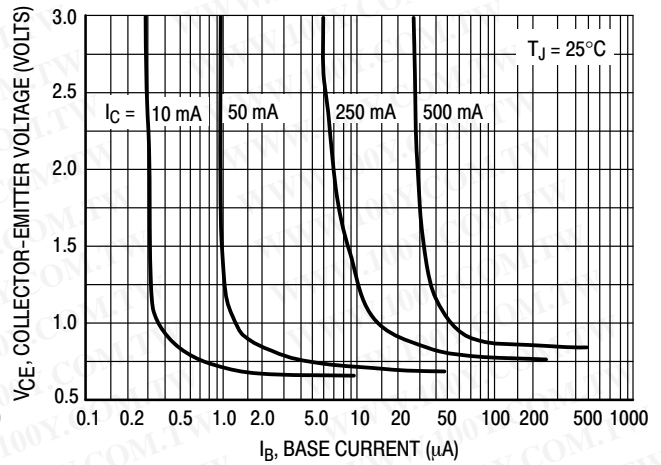


Figure 9. Collector Saturation Region

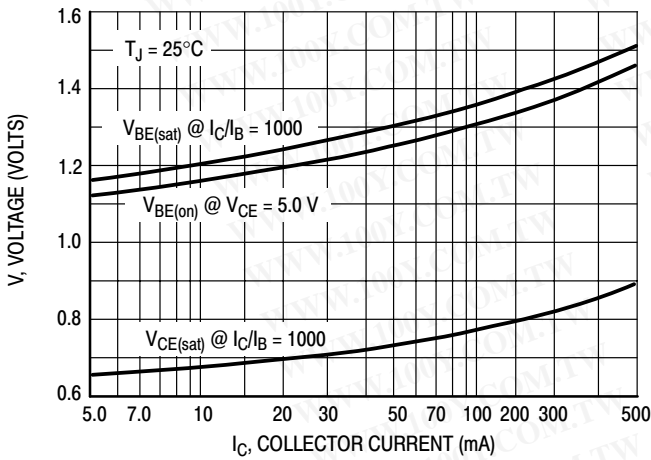


Figure 10. "On" Voltages

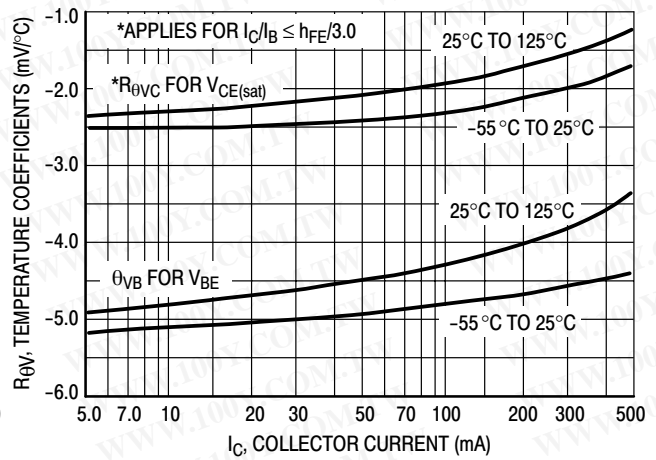


Figure 11. Temperature Coefficients

# MPSA13, MPSA14

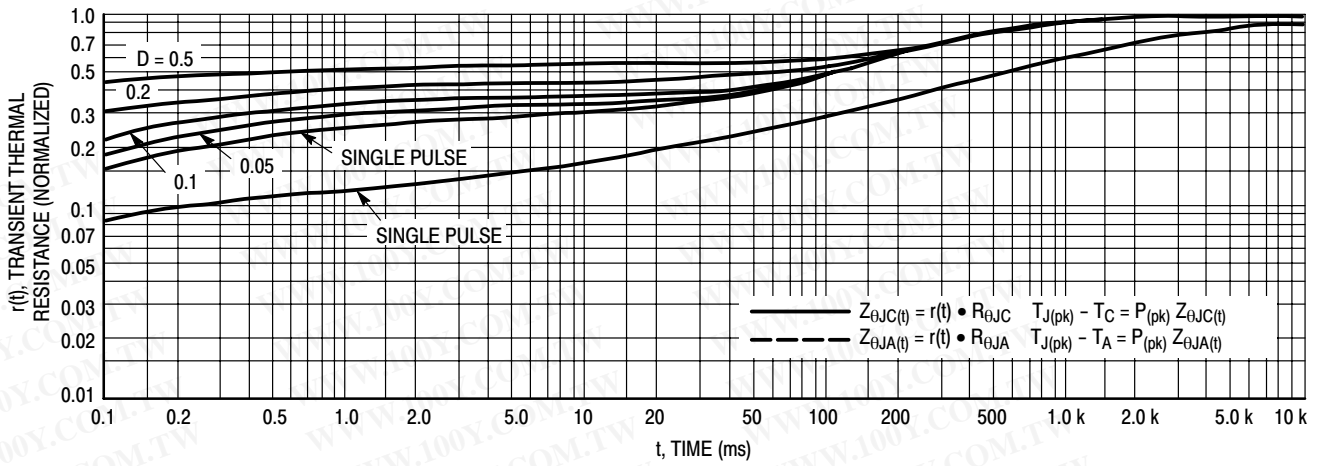


Figure 12. Thermal Response

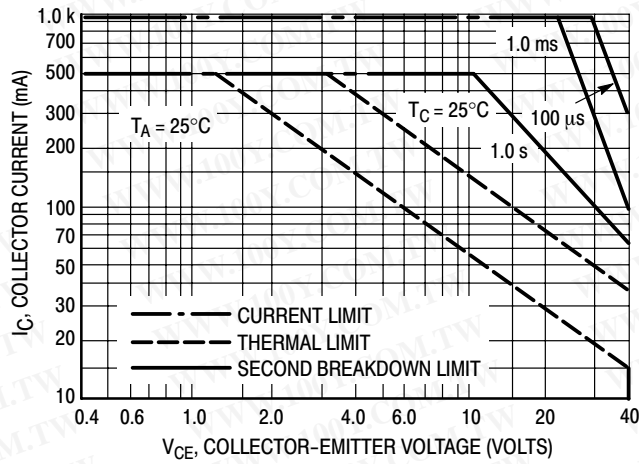
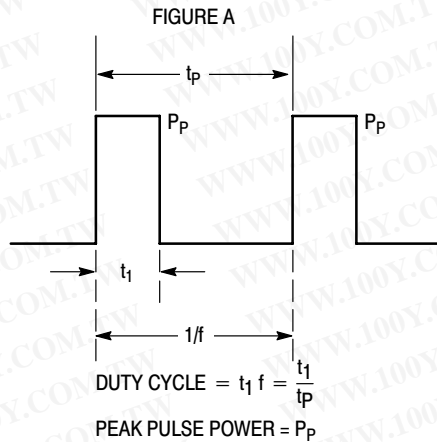


Figure 13. Active Region Safe Operating Area



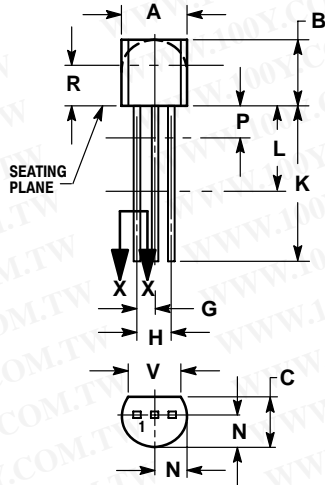
Design Note: Use of Transient Thermal Resistance Data

# MPSA13, MPSA14

## PACKAGE DIMENSIONS

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 勝特力电子(深圳) 86-755-83298787  
[Http://www.100y.com.tw](http://www.100y.com.tw)

TO-92 (TO-226)  
 CASE 29-11  
 ISSUE AM

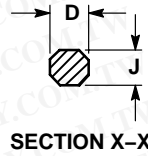


STRAIGHT LEAD  
 BULK PACK

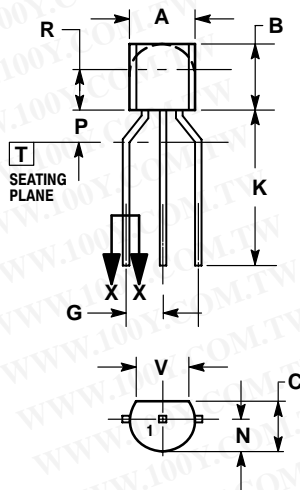
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---



SECTION X-X

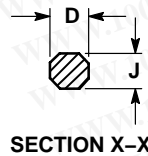


BENT LEAD  
 TAPE & REEL  
 AMMO PACK

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	MILLIMETERS	
	MIN	MAX
A	4.45	5.20
B	4.32	5.33
C	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	---
N	2.04	2.66
P	1.50	4.00
R	2.93	---
V	3.43	---



SECTION X-X

STYLE 1:

1. PIN 1. EMITTER
2. BASE
3. COLLECTOR

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